

# SANYO Semiconductors

DATA SHEET



# N-Channel Silicon MOSFET EFC4602 — General-Purpose Switching Device **Applications**

# **Features**

- 2.5V drive.
- Best suited for LiB charging and discharging switch.
- Common-drain type.

### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Source-to-Source Voltage	VSSS		20	V
Gate-to-Source Voltage	VGSS		±12	V
Source Current (DC)	IS		6	А
Source Current (Pulse)	ISP	PW≤100μs, duty cycle≤1%	60	A
Total Dissipation	PT	When mounted on ceramic substrate (5000mm <sup>2</sup> ×0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Cumhal	Conditions		Ratings			Unit
Parameter	Symbol			min	typ	max	Unit
Source-to-Source Breakdown Voltage	V(BR)SSS	IS=1mA, VGS=0V	Test Circuit 1	20			V
Zero-Gate Voltage Source Current	ISSS	VSS=20V, VGS=0V	Test Circuit 1			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>SS</sub> =0V	Test Circuit 2			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>SS</sub> =10V, I <sub>S</sub> =1mA	Test Circuit 3	0.5		1.3	V
Forward Transfer Admittance	yfs	VSS=10V, IS=3A	Test Circuit 4	4.5	7.5		S
Static Source-to-Source On-State Resistance	R <sub>SS</sub> (on)1	IS=3A, VGS=4.5V	Test Circuit 5	19.5	28	36.5	mΩ
	RSS(on)2	IS=3A, VGS=4.0V	Test Circuit 5	20	29	38	mΩ
	RSS(on)3	IS=1.5A, VGS=3.1V	Test Circuit 5	23	33	43	mΩ
	R <sub>SS</sub> (on)4	IS=1.5A, VGS=2.5V	Test Circuit 5	23	38	53.5	mΩ

Marking : FB

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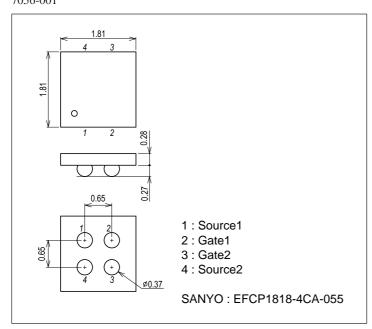
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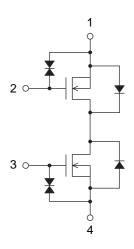
Parameter	Symbol	Conditions		Ratings			Unit
				min	typ	max	
Input Capacitance	Ciss	VSS=10V, f=1MHz	Test Circuit 8		1000		pF
Output Capacitance	Coss	V <sub>SS</sub> =10V, f=1MHz	Test Circuit 8		180		pF
Reverse Transfer Capacitance	Crss	V <sub>SS</sub> =10V, f=1MHz	Test Circuit 8		140		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.	Test Circuit 7		23		ns
Rise Time	tr	See specified Test Circuit.	Test Circuit 7		185		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.	Test Circuit 7		160		ns
Fall Time	tf	See specified Test Circuit.	Test Circuit 7		200		ns
Total Gate Charge	Qg	VSS=10V, VGS=10V, IS=6A			13		nC
Forward Source-to-Source Voltage	VF(S-S)	IS=6A, VGS=0V	Test Circuit 6		0.78	1.2	V

# Package Dimensions

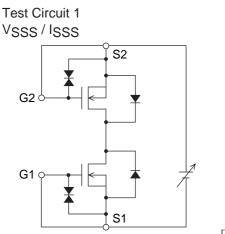
unit : mm (typ) 7056-001



#### **Electrical Connection**

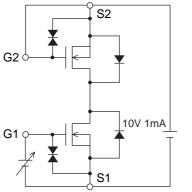


#### Test Circuits are example of measuring FET1 side



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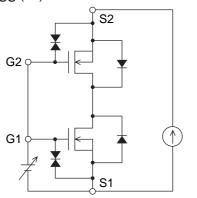
Test Circuit 3 VGS (off)



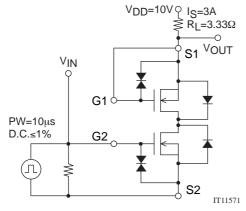
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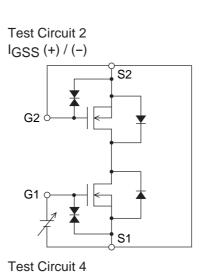
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Test Circuit 5 RSS (on)



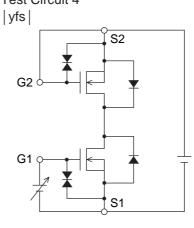
Test Circuit 7  $t_d$  (on),  $t_r$ ,  $t_d$  (off),  $t_f$ 



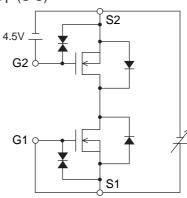


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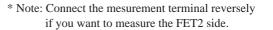
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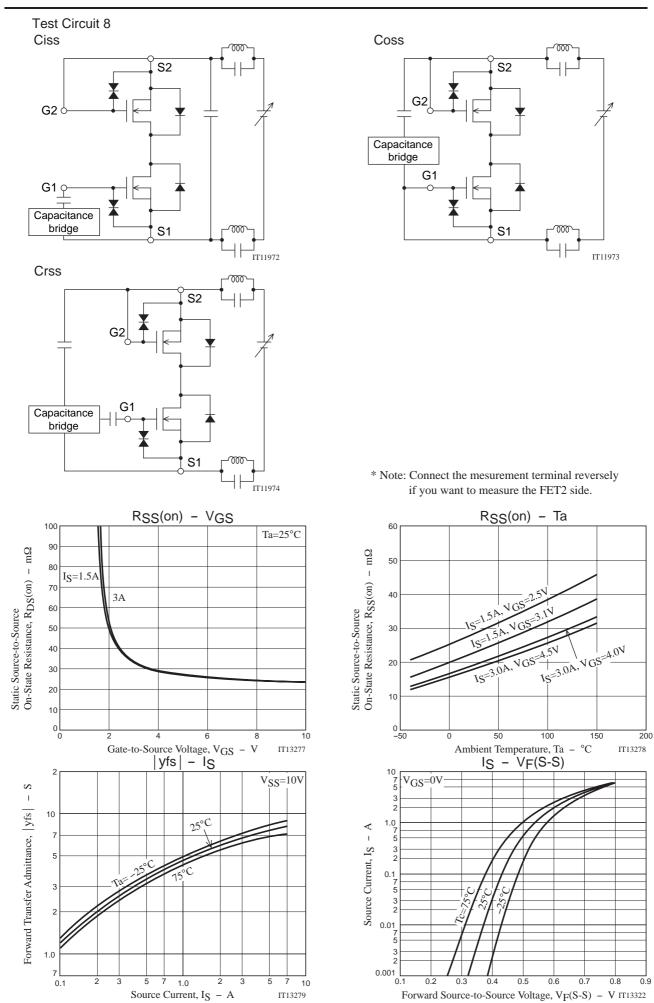


Test Circuit 6 VF (S-S)

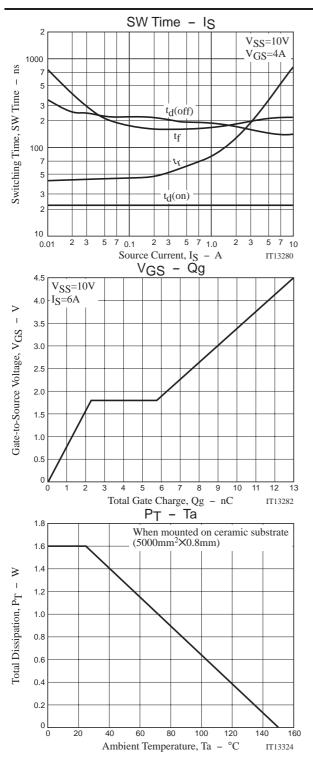


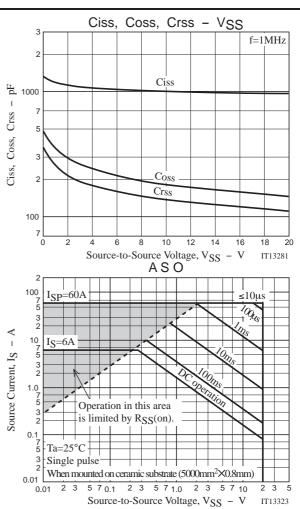
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No. A1048-4/6





Note on usage : Since the EFC4602 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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